



1A, 50V - 1000V High Efficient Surface Mount Rectifier

FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low profile Package
- Low power loss, high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

MECHANICAL DATA

- Case: Sub SMA
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- · Polarity: Indicated by cathode band
- Weight: 0.019g (approximately)

| KEY PARAMETERS | | | | |
|--------------------|------------|------|--|--|
| PARAMETER | VALUE | UNIT | | |
| I _F | 1 | Α | | |
| V_{RRM} | 50 - 1000 | V | | |
| I _{FSM} | 30 | Α | | |
| T _{J MAX} | 150 | °C | | |
| Package | Sub SMA | | | |
| Configuration | Single die | | | |









Sub SMA



| PARAMETER | SYMBOL | HS | HS | HS | HS | HS | HS | HS | HS | UNIT |
|--|---------------------|-------------------------------|-----|-----|-----|-----|-----|-----|------|------|
| | | 1AL | 1BL | 1DL | 1FL | 1GL | 1JL | 1KL | 1ML | |
| Marking code on the device | | HAL | HBL | HDL | HFL | HGL | HJL | HKL | HML | |
| Repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 300 | 400 | 600 | 800 | 1000 | V |
| Reverse voltage, total rms value | V _{R(RMS)} | 35 | 70 | 140 | 210 | 280 | 420 | 560 | 700 | V |
| Forward current | I _F | 1 | | | | Α | | | | |
| Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load | I _{FSM} | 30 | | | | А | | | | |
| Junction temperature | T_J | T _J - 55 to +150 | | | °C | | | | | |
| Storage temperature | T _{STG} | T _{STG} - 55 to +150 | | | | °C | | | | |



| THERMAL PERFORMANCE | | | | | |
|--|-----------------|-----|------|--|--|
| PARAMETER | SYMBOL | TYP | UNIT | | |
| Junction-to-ambient thermal resistance | $R_{\Theta JA}$ | 100 | °C/W | | |

| PARAMETER | | CONDITIONS | SYMBOL | TYP | MAX | UNIT |
|---|---|--|------------------|-----|------|------|
| (1) | HS1AL HS1BL HS1DL HS1FL | | V _F | - | 0.95 | V |
| Forward voltage ⁽¹⁾ | HS1GL | I _F = 1A, T _J = 25°C | | - | 1.30 | V |
| | HS1JL HS1KL HS1ML | | | - | 1.70 | V |
| Reverse current @ rated V _R ⁽²⁾ | | T _J = 25°C | | - | 5 | μΑ |
| | | T _J = 125°C | - I _R | - | 150 | μA |
| Junction capacitance | HS1AL HS1BL HS1DL HS1FL HS1GL | 1MHz, V _R = 4.0V | C ² | 20 | - | pF |
| | HS1JL HS1KL HS1ML | | | 15 | - | pF |
| Reverse recovery time | HS1AL HS1BL HS1DL HS1FL HS1GL | IF = 0.5A, IR = 1.0A, I _{rr} = 0.25A | t _{rr} | - | 50 | ns |
| | HS1JL HS1KL HS1ML | | | - | 75 | ns |

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

| ORDERING INFORMATION | | | | |
|------------------------------|---------|----------------------|--|--|
| ORDERING CODE ⁽¹⁾ | PACKAGE | PACKING | | |
| HS1xL | Sub SMA | 10,000 / Tape & Reel | | |

Notes:

1. "x" defines voltage from 50V(HS1AL) to 1000V(HS1ML)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

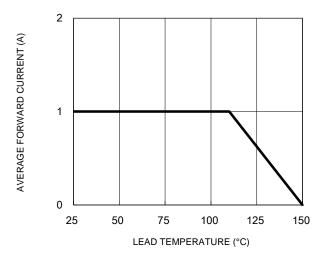


Fig.3 Typical Reverse Characteristics

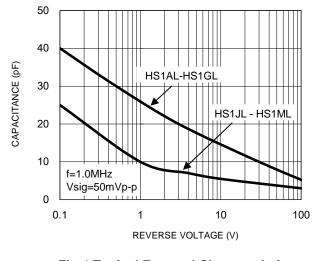
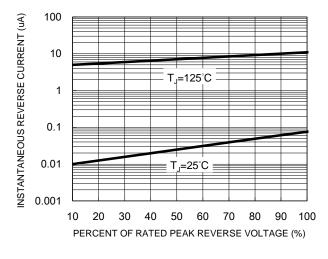


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics



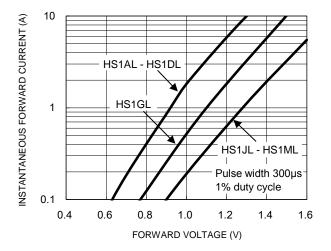
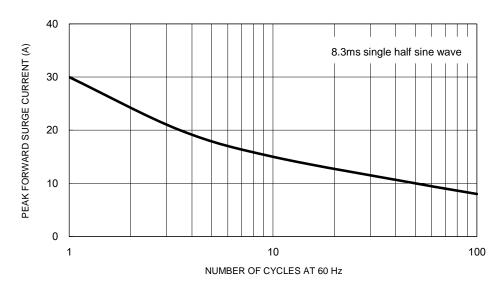


Fig.5 Maximum Non-Repetitive Forward Surge Current



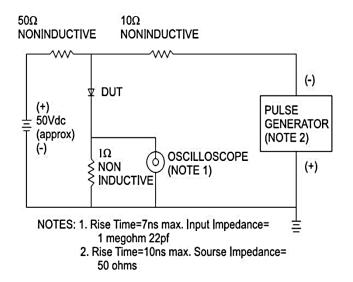


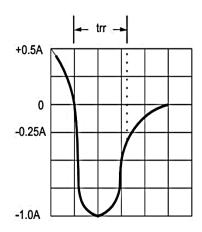
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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



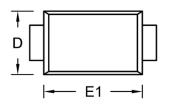


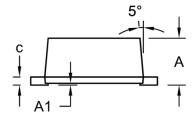


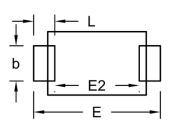


PACKAGE OUTLINE DIMENSIONS

Sub SMA

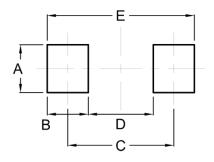






| DIM. | Unit (mm) | | Unit (| (inch) | |
|-------|-----------|------|--------|--------|--|
| DIWI. | Min. | Max. | Min. | Max. | |
| Α | 1.23 | 1.43 | 0.048 | 0.056 | |
| A1 | 0.00 | 0.10 | 0.000 | 0.004 | |
| b | 0.80 | 1.20 | 0.031 | 0.047 | |
| С | 0.16 | 0.30 | 0.006 | 0.012 | |
| D | 1.70 | 1.90 | 0.067 | 0.075 | |
| E | 3.40 | 3.80 | 0.134 | 0.150 | |
| E1 | 2.70 | 2.90 | 0.106 | 0.114 | |
| E2 | 2.45 | 2.60 | 0.096 | 0.102 | |
| L | 0.35 | 0.85 | 0.014 | 0.033 | |

SUGGESTED PAD LAYOUT



| Symbol | Unit (mm) | Unit (inch) |
|--------|-----------|-------------|
| Α | 1.40 | 0.055 |
| В | 1.20 | 0.047 |
| С | 3.10 | 0.122 |
| D | 1.90 | 0.075 |
| E | 4.30 | 0.169 |

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

ΥW = Date Code F = Factory Code





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